Diode
Fast

RoHS Compliant

Features:

- Glass passivated chip junction
- High efficiency, low V_F
- High current capability
- High reliability
- High surge current capability
- For use in low voltage, high frequency inventor, free wheeling, and polarity protection application

Specifications:

Mechanical Data:

Cases	: Moulded plastic
Lead	: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
Polarity	: Colour band denotes cathode end
High temperature soldering guaranteed	: 260°C/10 seconds/0.375", (9.5mm) lead lengths at 5lbs., (2.3kg) tension
Mounting position	: Any
Weight	: 1.1g

Maximum Ratings and Electrical Characteristics:

Rating at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

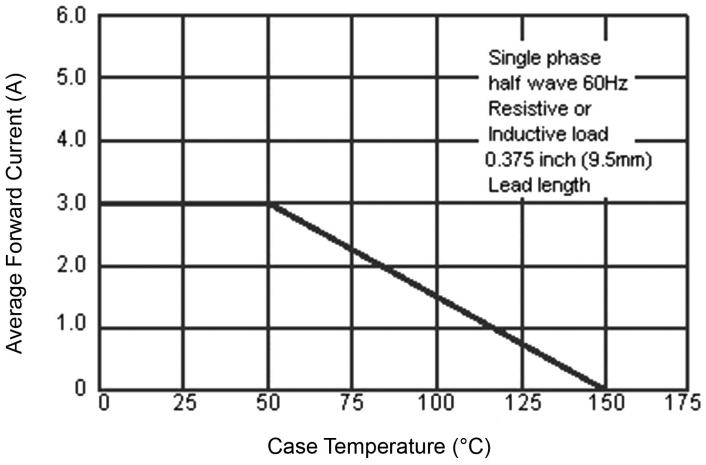
Type Number	Symbol	HER305G	HER306G	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	400	600	V
Maximum RMS Voltage	V_{RMS}	280	420	
Maximum DC Blocking Voltage	V_{DC}	400	600	
Maximum Average Forward Rectified Current 0.375" (9.5mm) Lead Length at T_A = 55°C	$I_{(AV)}$	3		A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	125		
Maximum Instantaneous Forward Voltage at 3A	V_F	1.3	1.7	V

Type Number	Symbol	HER305G	HER306G	Units
Maximum DC Reverse Current at T_A = 25°C at Rated DC Blocking Voltage at T_A = 125°C	I_R	10 200		µA µA
Maximum Reverse Recovery Time (Note 1)	T_{rr}	50	75	nS
Typical Junction Capacitance (Note 2)	C_j	60	35	pF
Typical Thermal Resistance (Note 3)	$R_{\theta JA}$ $R_{\theta JL}$	35 10		°C/W
Operating Temperature Range	T_J / T_{STG}	-65 to +150		°C

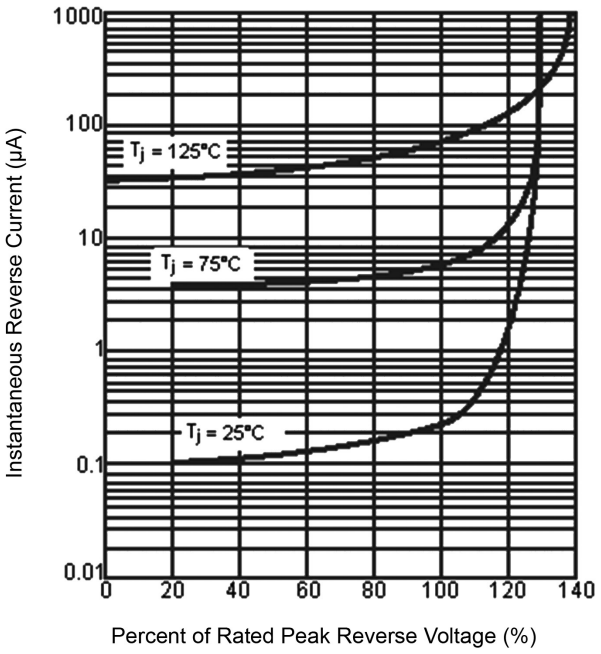
Note: 1. Reverse Recovery Test Conditions: I_F = 0.5A, I_R = 1A, I_{RR} = 0.25A.
Note: 2. Measured at 1MHz and Applied Reverse Voltage of 4V DC.
Note: 3. Mount on Cu-Pad Size 16mm × 16mm on PCB.

Ratings and Characteristic Curves (HER305G, HER306G)

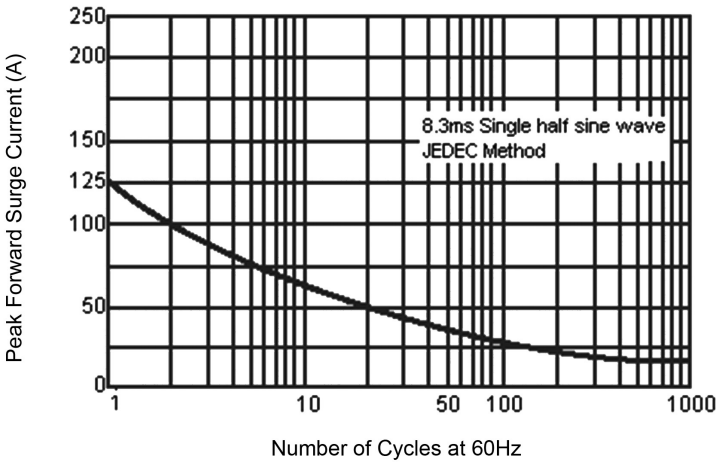
Maximum Forward Current Derating Curve



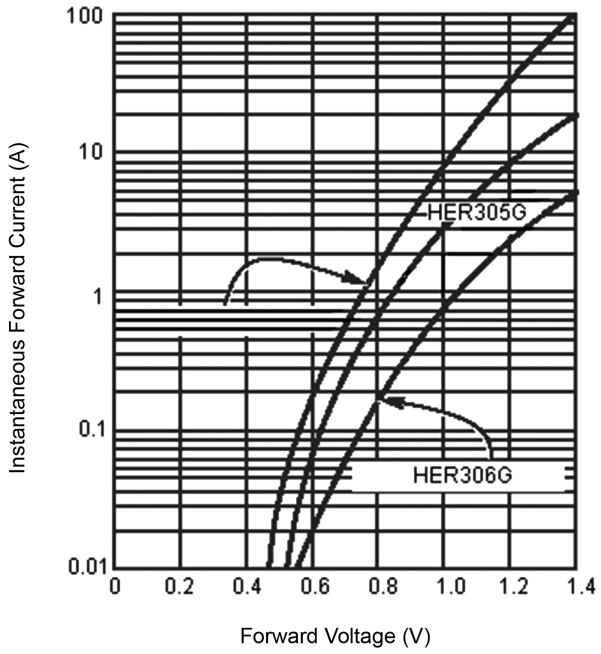
Typical Reverse Characteristics



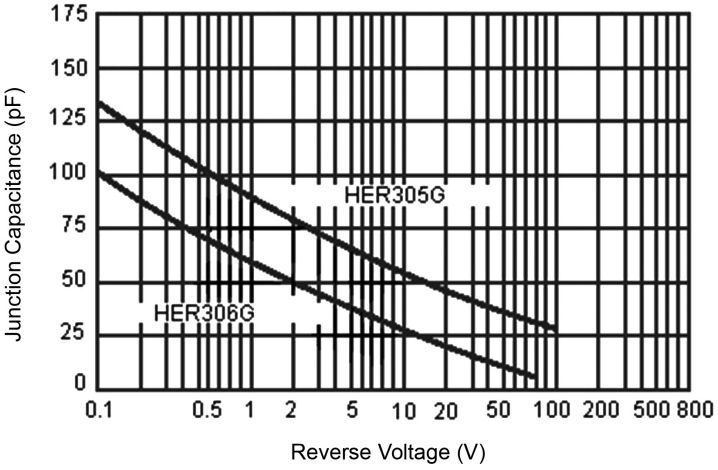
Maximum Non-Repetitive Forward Surge Current



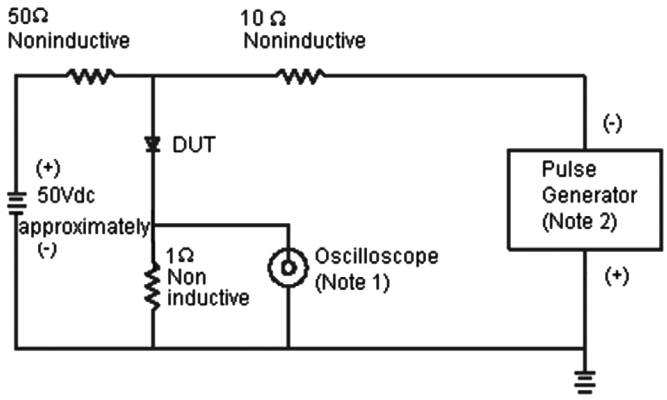
Typical Instantaneous Forward Characteristics

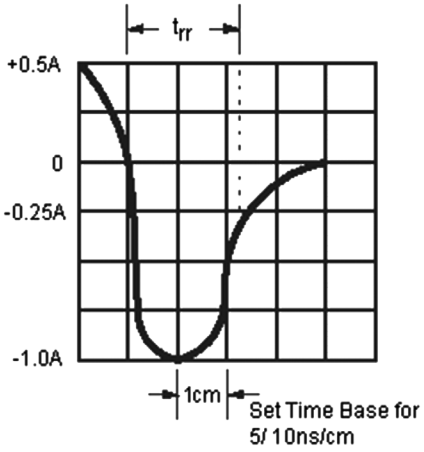


Typical Junction Capacitance



Reverse Recovery Time Characteristic and Test Circuit Diagram





Note: 1. Rise Time = 7ns Maxitmum. Input Impedance = 1MΩ 22pf
Note: 2. Rise Time = 10ns Maximum Source Impedance = 50Ω

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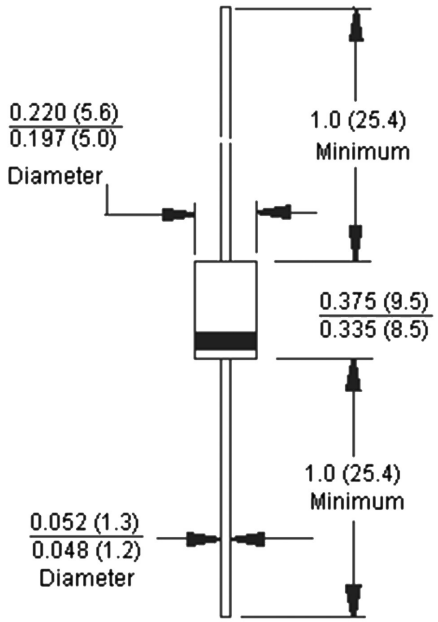

Dimensions : Inches (Millimetres)

Part Number Table

Description	Part Number
Diode, Fast, 3A, 400V	HER305G
Diode, Fast, 3A, 600V	HER306G